

Determination of strength of interface in packages based on an approach using coupling of experimental and modelling results

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Purpose

- **Modelling is commonly used to predict lifetime of packages (component & assembly), but encounters some difficulties & issues :**
 - **Predictive reliability mostly dedicated to solder joints, and failure of interfaces (links between 2 materials) is often neglected**
 - **Parameters (material, manufacturing steps ...) are sometimes unknown, and thus difficult to implement in models**
 - **In most cases, mechanical stresses induced by manufacturing process are not taken into account**

Outline

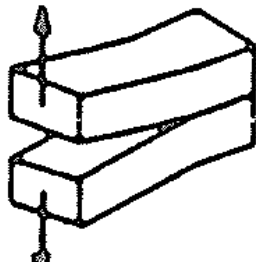
- **Introduction and Objectives**
- **Sample selection and preparation**
- **Experimental approach**
- **Modelling approach**
- **Conclusion**

Introduction

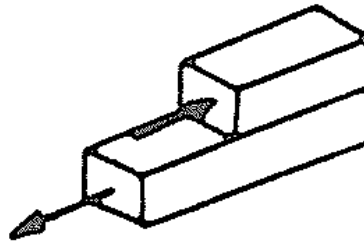
- **Improve modelling calculation accuracy to have the more realistic prediction of electronic assemblies lifetime behavior**
- **The idea is to use real measurement results (real stressed states) to adjust, implement, and verify models.**

Sample selection and preparation

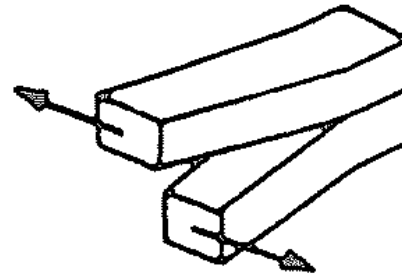
- Crack driven by two parameters
 - σ_t : traction (normal to interface crack)
 - τ_r : shear (in plane of interface crack)



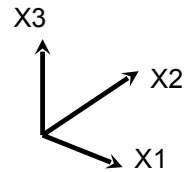
**Mode I
Tensile**



**Mode II
Shear**



**Mode III
Shear**



Sample selection and preparation

- Criteria for initiation of debonding :
 - Allows to take into account all the modes of stress of the crack

$$(\sigma/\sigma_c)^2 = (\sigma_{33} |\sigma_{33}| / \sigma_t^2 + (\sigma_{12}^2 + \sigma_{23}^2)/\tau_r^2)$$

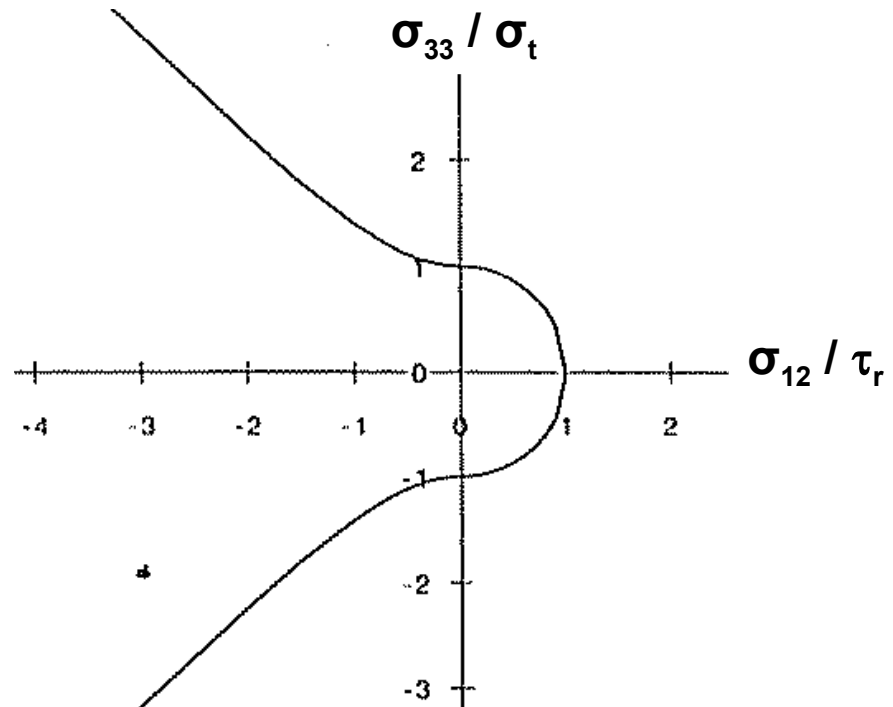
σ_t = traction stress

τ_r = shear stress

σ_{ij} for $i,j=1$ to 3 = stress tensor

σ_c = critical stress

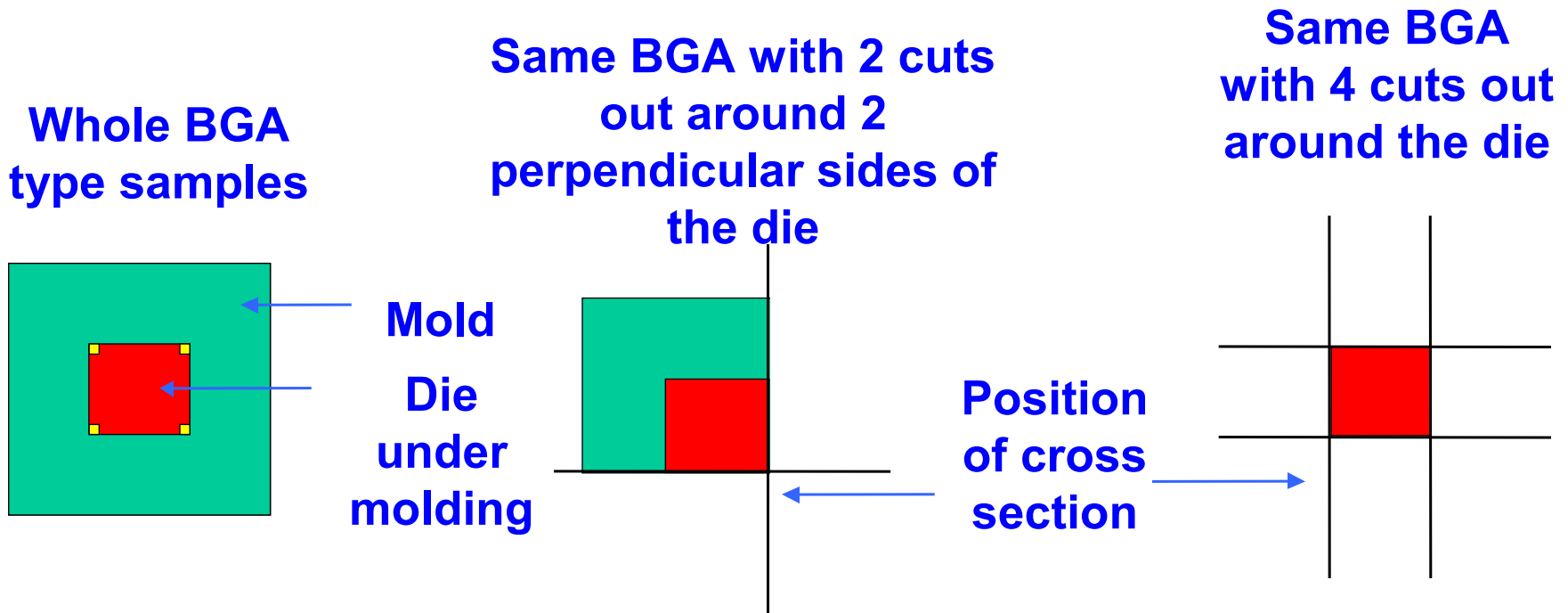
σ = maximal stress



Crack criteria curve

Sample selection and preparation

- It has been decided to work on the basis of real, but simple, components : BGA with one die, with specific preparation.
- Two types of cutting have been realized through the component in order to amplify and differentiate stresses and debonding in the component.

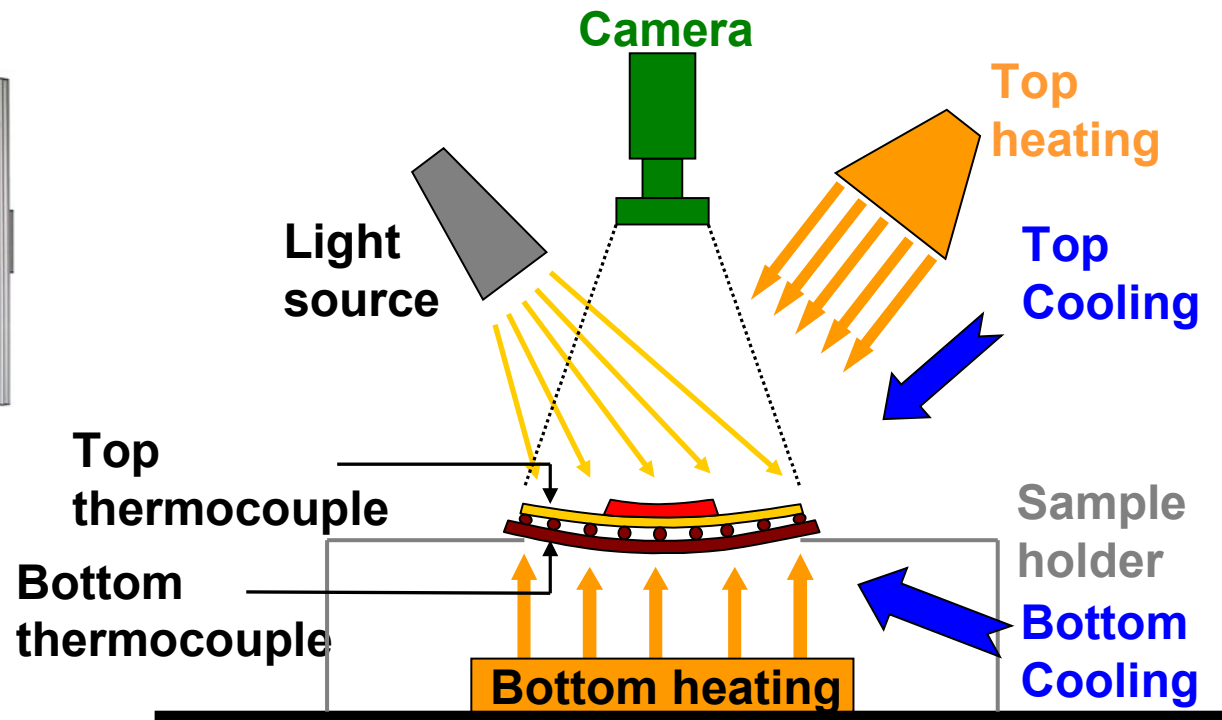


Experimental results

- **Measurement Techniques**
 - **Inspection using scanning acoustic microscopy is the only non destructive method to detect delamination in electronics components: BGA, Flip chip, SOI, Mems...**
 - **TDM is a tool developed by Insidix able to measure sample topography and deformation at the same time as a thermal stress is applied. Thus, one can have a “live” overview of samples behaviour during reflow or gluing process, during aging tests, ...**

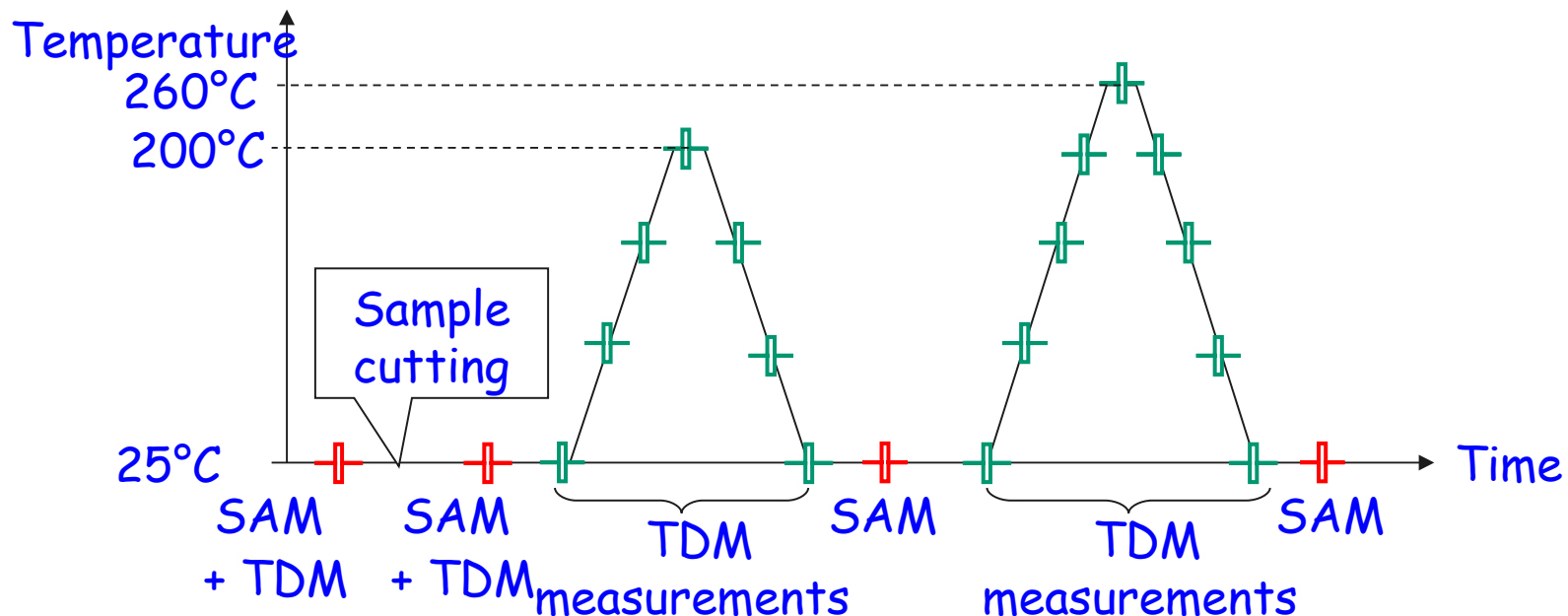
Experimental results

- High resolution and fast full field optical measurement (absolute and relative)
- Stable and manageable oven
- As representative as possible to real samples thermo-mechanical stress (Jedec profiles, etc)



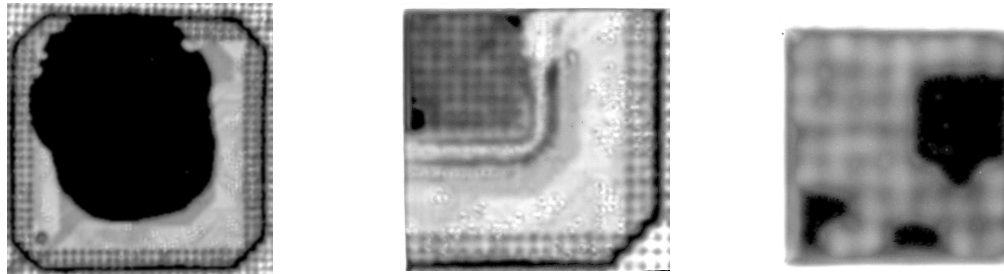
Experimental results

- Experiments
 - SAM of BGA before sample preparation,
 - SAM after sample preparation
 - Thermal stress, low speed :
 - TDM during heating up to 200°C + SAM back to 25°C
 - TDM during heating up to 260°C + SAM back to 25°C



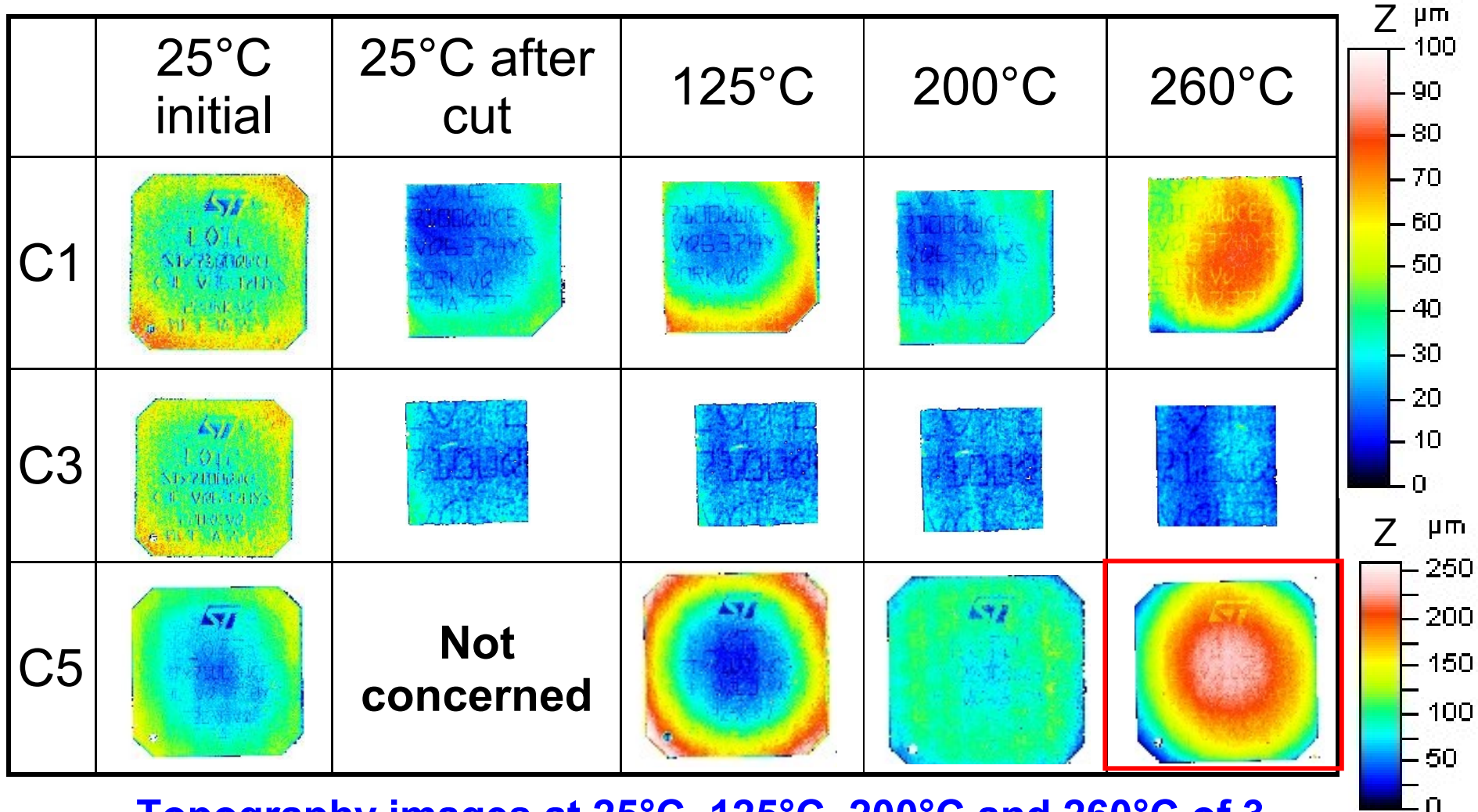
Experimental results

- **SAM**
 - No delamination or heterogeneity detected at initial state, after sample cut, and after heating up to 200°C
 - Delamination after the second thermal cycle, at die / substrate interface (die attach) for all samples, and also at molding compound/substrate for complete BGA.



Through mode images after 260°C thermal cycle – black areas indicates delamination in the package. From left to right : whole BGA (large interface crack), BGA with 2 cuts along die, BGA with 4 cuts around the die

Experimental results



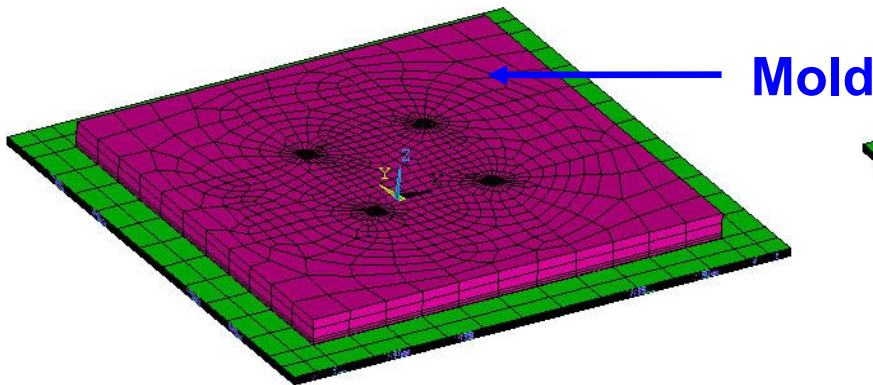
Topography images at 25°C, 125°C, 200°C and 260°C of 3 samples (BGA with 2 cuts along die, BGA with 4 cuts around the die, whole BGA)

Experimental results

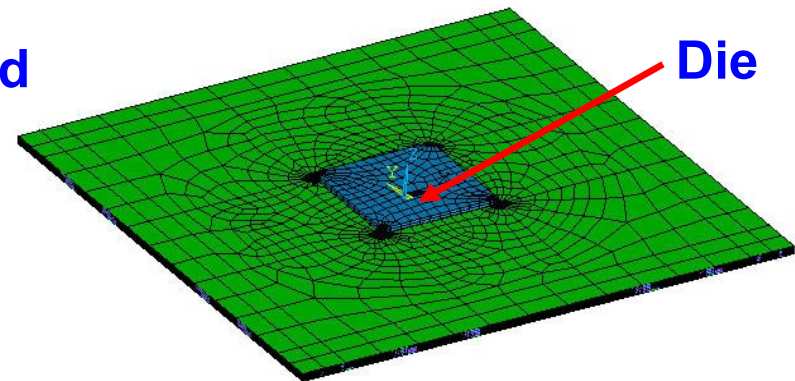
- The components were concave at initial state. The amplitude varies from $-30\mu\text{m}$ to $-50\mu\text{m}$.
- These surface geometries and the differences between one component to another one are due to residual stress after production.
- When the sample is cut, warpage variations are different, because strain at boundaries and also neutral fibre are not the same.
- Warpage variations before and after glass transition (T_g) are often different – here it causes 4 increasing and decreasing of warpage between 25°C and 260°C , stressing then the interfaces.

Modelling approach

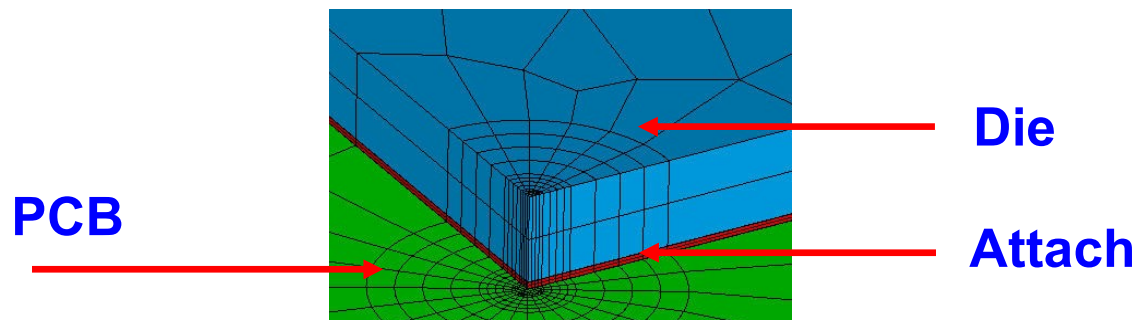
- The component has been represented fully in order to have a displacement profile with or without cutting it
- Materials properties are thermo-elastic



Finite elements model



Model without mold



Zoom at attach corner

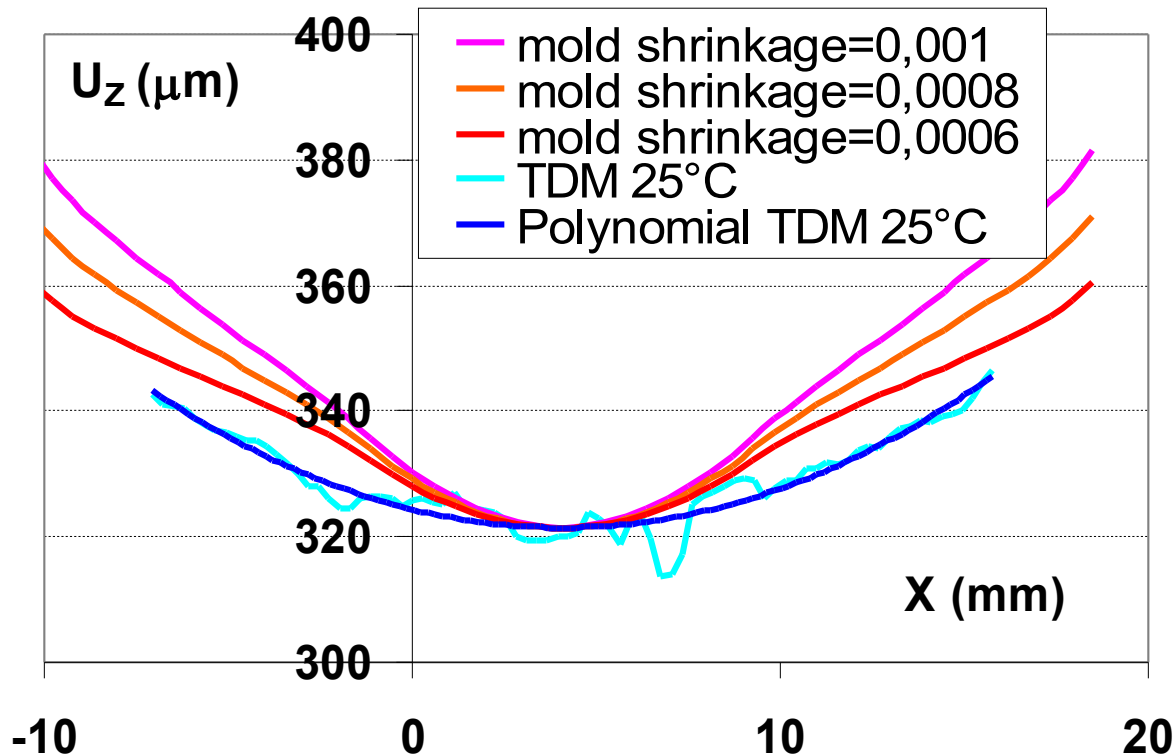
Modelling approach

Procedure steps

- ✂ **Fab. process : die report on lead-frame (up to 275°C) & encapsulation (up to 180°C).**
- ✂ **Influence of 3 parameters (mold & glue shrinkage, CTE_{mold} with Topography measurements at 25°C**
- ✂ **Cutting of samples and thermal loads**
- ✂ **Calculation and adjustment of parameters on the whole component**
- ✂ **Calculations and checks of results on cut components**

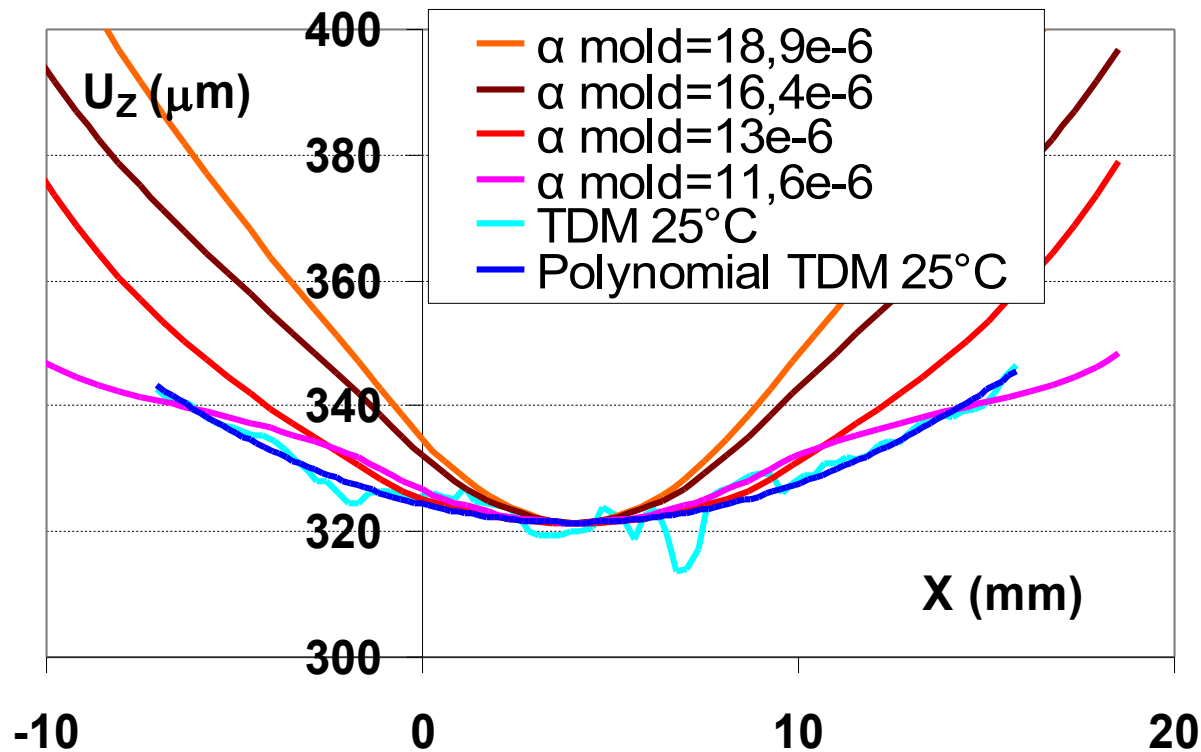
Influence of 3 parameters

- Influence of the 3 parameters for the adjustment:
 - Mold shrinkage: large impact on mold deformation, curvatures increases with mold shrinkage



Influence of 3 parameters

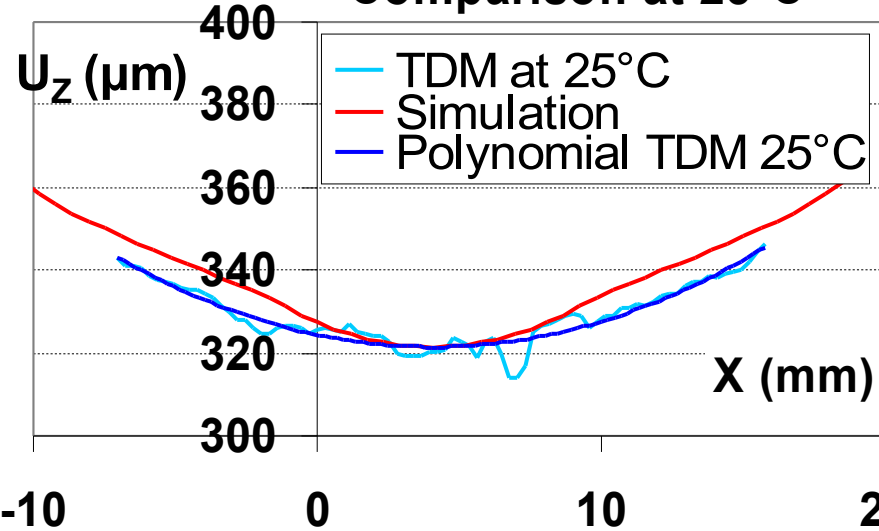
- CTE_{Mold} : large impact on mold deformation, curvatures increases with the Coefficient of Thermal Expansion. Compared to mold shrinkage effect, CTE has wider effect.



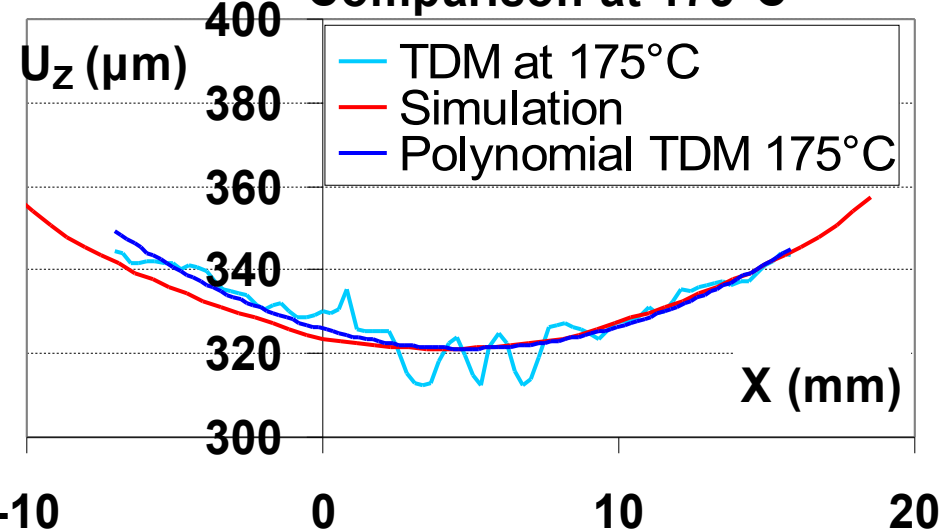
- Glue shrinkage: the impact is negligible

Calculations and adjustments on whole component

Comparison at 25°C

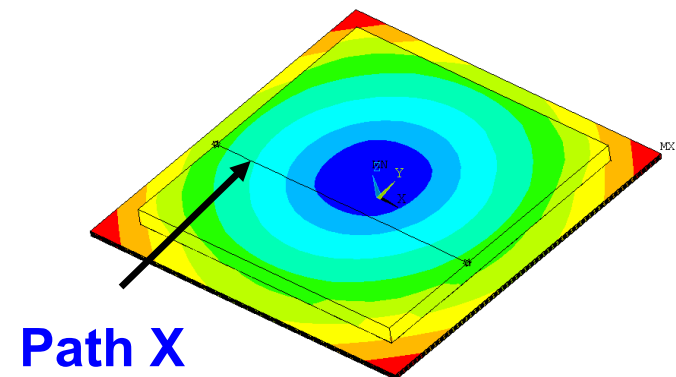


Comparison at 175°C



Final adjustment of displacement for the whole component

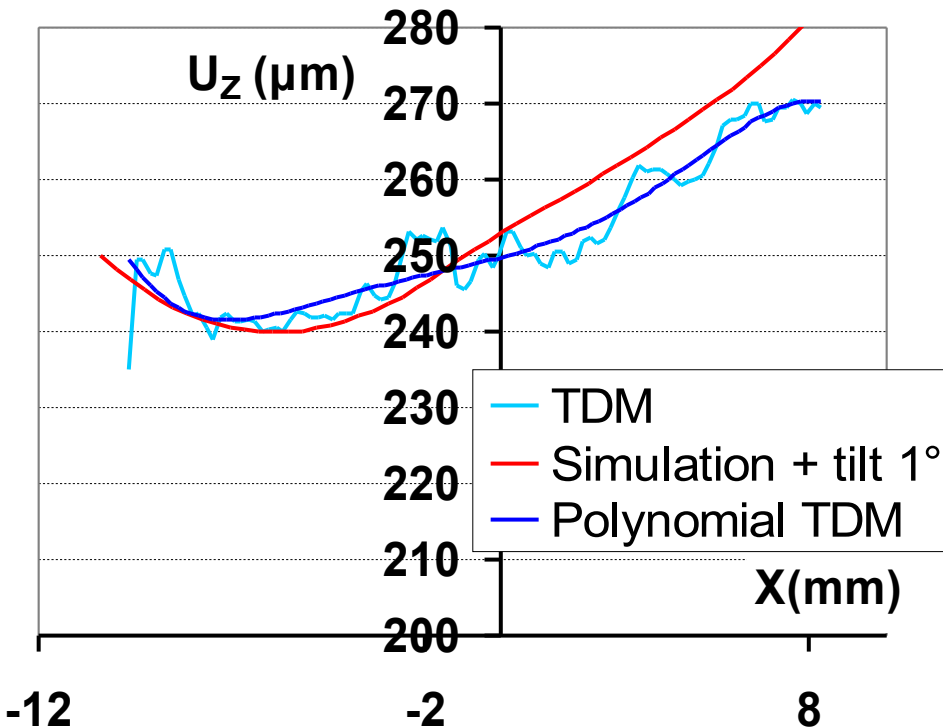
- Simulation curves (in red) are fitted with the following parameters:
 - mold shrinkage: 0.05%
 - glue shrinkage: 0.3%
 - CTE_{Mold} at 25°C = 13 ppm



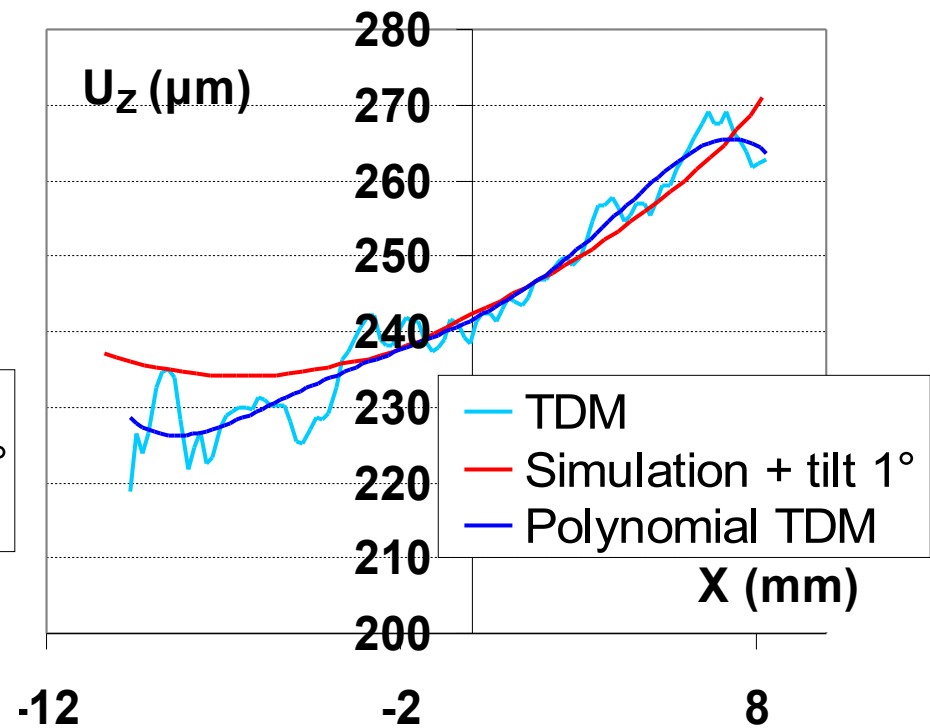
Check on cut component

- Adjustments of shrinkage is checked after the cutting at 25°C and 175°C

Comparison at 25°C



Comparison at 175°C

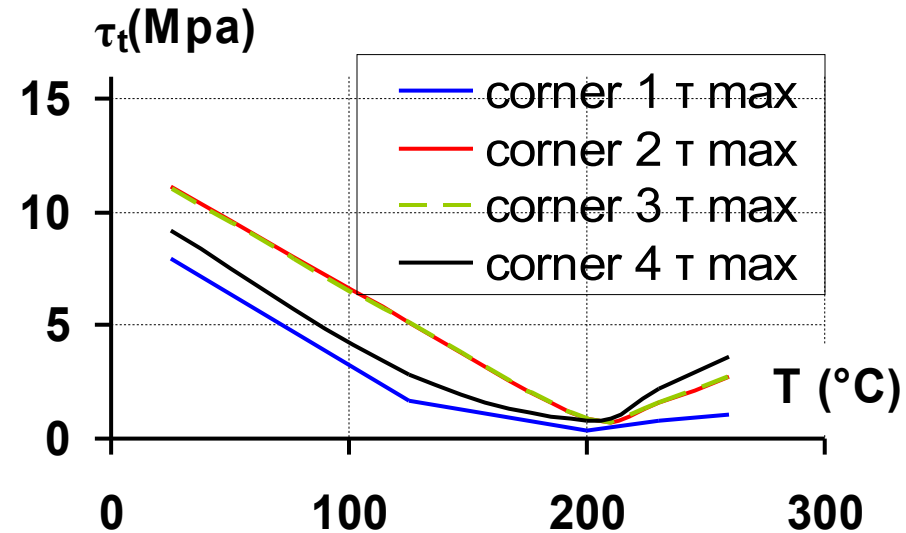
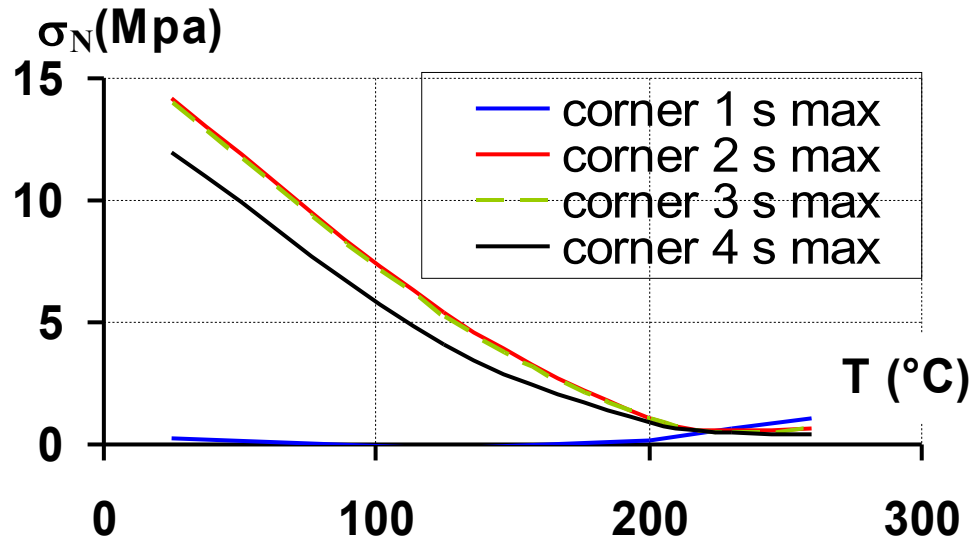


Adjustment of displacement for the cut component

- Simulation curves rather fit measurements, with a small difference at the “free” corner.

Stress values for cut component

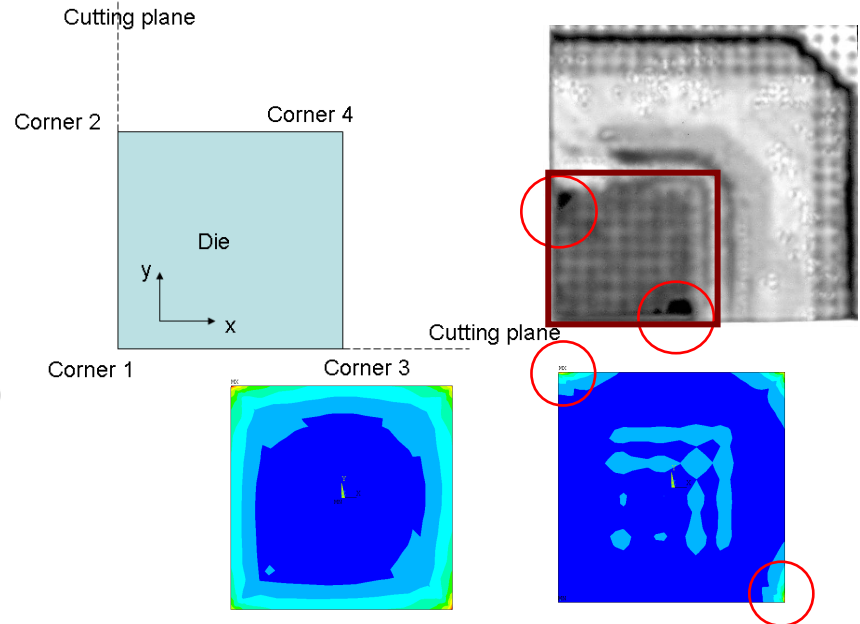
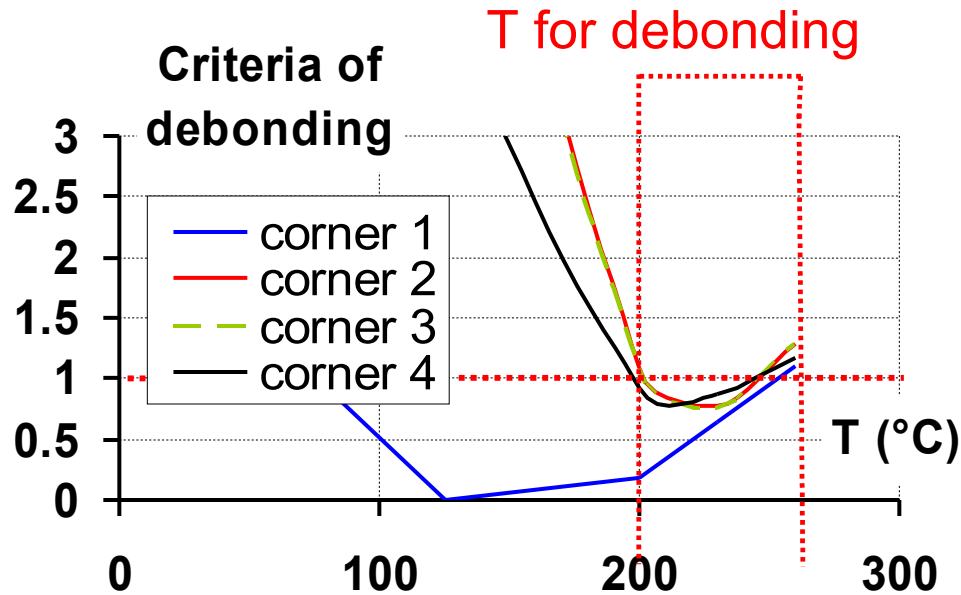
- To compute failure behavior, maximum stresses at the interfaces have to be determined.



Variation of normal and tangential stresses at the 4 corners of die/glue interface during temperature cycling

- Same maximal stress values are observed at 25 $^{\circ}\text{C}$
- These graphs show that corners 2 and 3 are the most stressed.

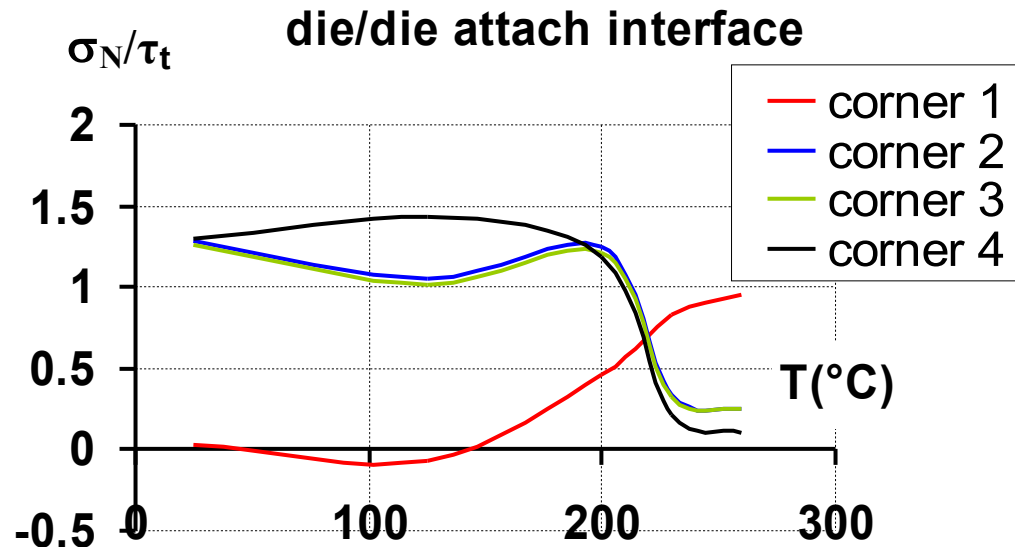
Criteria of debonding



Criteria of debonding variation at the 4 corners of die/die attach interface during temperature cycling

- Debonding observed with SAM measurements in corners 2 and 3 confirms the simulated behaviour.
 - Measurements show that debonding occurs during the 2nd thermal cycle (260°C)
- ✂ ➔ Consequently, the stress limit at interface debonding depends on temperature

Criteria of debonding



**σ/τ ratio variation at the 4 corners
of die/glue interface during temperature cycling**

- Criteria of debonding is linked with σ/τ ratio, at 170°C this ratio is similar for corner 2, 3 and 4.
- Difficult to distinguish σ and τ effect in the criteria of debonding

Conclusions

- **This study has permitted to improve modelling calculations by the use of experimental data.**
- **Simulation predicts starting location of debonding.**
- **It has been shown also that the stress limit at interface debonding depends on temperature.**
- **The method can be used at all levels (product development, reliability test, ...), and for whatever component or assembly.**
- **With this methodology, save time and money with more realistic lifetime evaluation.**